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Maximum Ratings

Approx Net Weight:70g

Parameter	Symbol	Grade			Unit
		PBF203	PBF206	PBF208	
Repetitive Peak Off-State Voltage	$V_{DRM}$	300	600	800	V
Non Repetitive Peak Off-State Voltage	$V_{DSM}$	400	700	960	
Repetitive Peak Reverse Voltage	$V_{RRM}$	300	600	800	V
Non Repetitive Peak Reverse Voltage	$V_{RSM}$	400	700	960	

Parameter	Symbol	Conditions	Max Rated Value	Unit
Average Rectified Output Current	$I_{O(AV)}$	50Hz Half Sine Wave condition $T_c=60^\circ\text{C}$	20	A
Surge On-State Current	$I_{TSM}$	50 Hz Half Sine Wave, 1Pulse, Non-Repetitive	160	A
I Squared t	$I^2t$	2msec to 10msec	128	$\text{A}^2\text{s}$
Critical Rate of Turned-On Current	$di/dt$	$V_D=2/3V_{DRM}$ , $I_{TM}=2I_o$ , $T_j=125^\circ\text{C}$ $I_c=100\text{mA}$ , $di/dt=0.2\text{A}/\mu\text{s}$	100	$\text{A}/\mu\text{s}$
Peak Gate Power	$P_{GM}$		5	W
Average Gate Power	$P_{G(AV)}$		0.5	W
Peak Gate Current	$I_{GM}$		2	A
Peak Gate Voltage	$V_{GM}$		10	V
Peak Gate Reverse Voltage	$V_{RGM}$		5	V
Operating Junction Temperature Range	$T_{jw}$		-40 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$		-40 to +125	$^\circ\text{C}$
Isolation Voltage	Viso	Base Plate to Terminals, AC1min	2000	V
Mounting torque	Case mounting	M5 Screw	2.4 to 2.8	N·m
	Terminals	-	-	

Value per 1 Arm



Electrical • Thermal Characteristics

Characteristics	Symbol	Test Conditions	Maximum Value			Unit
			Min.	Typ.	Max.	
Peak Off-State Current	$I_{DM}$	$V_{DM} = V_{DRM}$ , $T_j = 125^\circ\text{C}$			5	mA
Peak Reverse Current	$I_{RM}$	$V_{RM} = V_{RRM}$ , $T_j = 125^\circ\text{C}$			5	mA
Peak Forward Voltage	$V_{TM}$	$I_{TM} = 30\text{A}$ , $T_j = 25^\circ\text{C}$			1.63	V
Gate Current to Trigger	$I_{GT}$	$V_D = 6\text{V}$ , $I_T = 1\text{A}$	$T_j = -40^\circ\text{C}$		100	mA
			$T_j = 25^\circ\text{C}$		50	
			$T_j = 125^\circ\text{C}$		25	
Gate Voltage to Trigger	$V_{GT}$	$V_D = 6\text{V}$ , $I_T = 1\text{A}$	$T_j = -40^\circ\text{C}$		4	V
			$T_j = 25^\circ\text{C}$		2.5	
			$T_j = 125^\circ\text{C}$		2	
Gate Non-Trigger Voltage	$V_{GD}$	$V_D = 2/3V_{DRM}$ , $T_j = 125^\circ\text{C}$	0.25			V
Critical Rate of Rise of Off-State Voltage	$dv/dt$	$V_D = 2/3V_{DRM}$ , $T_j = 125^\circ\text{C}$	100			$\text{V}/\mu\text{s}$
Turn-Off Time	$t_q$	$I_{TM} = I_o$ , $V_D = 2/3V_{DRM}$ $dv/dt = 20\text{V}/\mu\text{s}$ , $V_R = 100\text{V}$ $-di/dt = 20\text{A}/\mu\text{s}$ , $T_j = 125^\circ\text{C}$		80		$\mu\text{s}$
Turn-On Time	$t_{gt}$	$V_D = 2/3V_{DRM}$ , $T_j = 125^\circ\text{C}$ $I_c = 100\text{mA}$ , $di/dt = 0.2\text{A}/\mu\text{s}$		6		$\mu\text{s}$
Delay Time	$t_d$			2		$\mu\text{s}$
Rise Time	$t_r$			4		$\mu\text{s}$
Latching Current	$I_L$	$T_j = 25^\circ\text{C}$		70		mA
Holding Current	$I_H$	$T_j = 25^\circ\text{C}$		50		
Thermal Resistance *1	$R_{th(j-c)}$	Junction to Case			1.1	$^\circ\text{C}/\text{W}$
	$R_{th(c-f)}$	Base Plate to Heat Sink with Thermal Compound			0.1	

Value Per 1Arm

\*1: Value Per Module

PBF20x OUTLINE DRAWING (Dimensions in mm)

